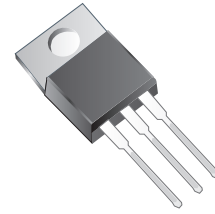


MBR20H100FCT-G Thru. MBR20H200FCT-G

Reverse Voltage: 100 to 200 V

Forward Current: 20 A

RoHS Device

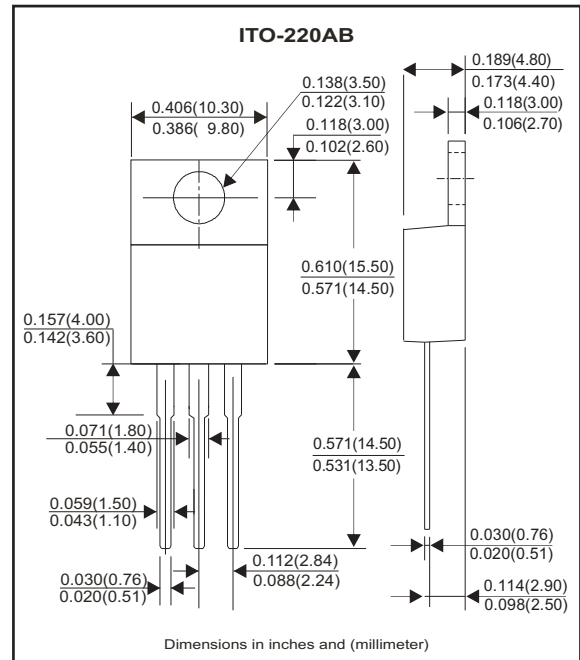


Features

- Plastic material used carries underwriters laboratory laboratory classifications 94V-0.
- Guard ring for transient protection.
- Low power loss high efficiency.
- High current capability, low forward voltage drop.
- High surge capacity.
- For use in power supply-output rectification, power management, instrumentation.
- Guarding for overvoltage protection.
- High temperature soldering guaranteed: 260°C/10 seconds, 0.25" (6.35mm) from case.

Mechanical Data

- Case: JEDEC ITO-220AB, molded plastic body.
- Terminals: Pure tin plated, lead free.Solderable per MIL-STD-750,Method 2026
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5in. -1bs.max
- Weight: 2.24 grams



Electrical Characteristics (at TA=25°C unless otherwise noted)

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load derate current by 20%.

Parameter	Symbol	MBR 20H100FC-G	MBR 20H150FCT-G	MBR 20H200FCT-G	Unit
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	100	150	200	V
Maximum RMS Voltage	V _{RMS}	70	105	14	V
Maximum DC Blocking Voltage	V _{DC}	100	150	200	V
Maximum Average Forward Rectified Current @ T _C =125°C	I _(AV)	20.0			A
Peak repetitive forward current (rated VR, square wave,20KHZ) at T _C =125°C	I _{FRM}	20.0			A
Peak Forward Surge Current , 8.3ms Single Half Sine-Wave Super Imposed On Rated Load(JEDEC Method)	I _{FSM}	150			A
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	1.0		0.5	A
Maximum Instantaneous forward voltage at: forward voltage at: (Note 2)	V _F	IF=10A@ T _J = 25°C	0.85		V
		IF=10A@ T _J =125°C	0.75		
		IF=20A@ T _J = 25°C	0.95		
		IF=20A@ T _J =125°C	0.85		
Maximum Instantaneous reverse current @ T _C = 25°C at Rate DC blocking voltage @ T _C = 125°C at (Note 2)	I _R	5			µA
		2			mA
Voltage rate kf change (Rated V _R)	dV/dt	10000			V/µS
Maximum Typical Thermal Resistance (Note3)	R _{θJC}	1.50			°C/W
Operating Junction Temperature Range	T _J	-65 to +175			°C
Storage Temperature Range	T _{STG}	-65 to +175			°C

NOTES:

1. 2.0us Pulse Width, f=1.0 KHz.
2. Pulse test: 300us pulse width, 1% duty cycle.
3. Thermal Resistnce from junction to case per leg,Mount on heatsink size of 2in*3in*0.25in Al-plate.

RATING AND CHARACTERISTIC CURVES (MBR20H100FCT-G Thru. MBR20H200FCT-G)

FIG.1- Forward Current Derating Curve

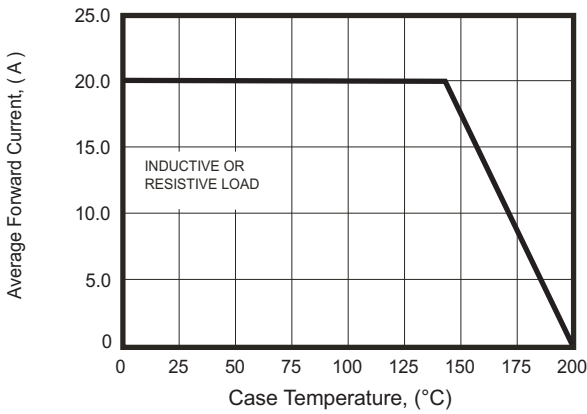


FIG.2- Maximum Non-Repetitive Surge Current

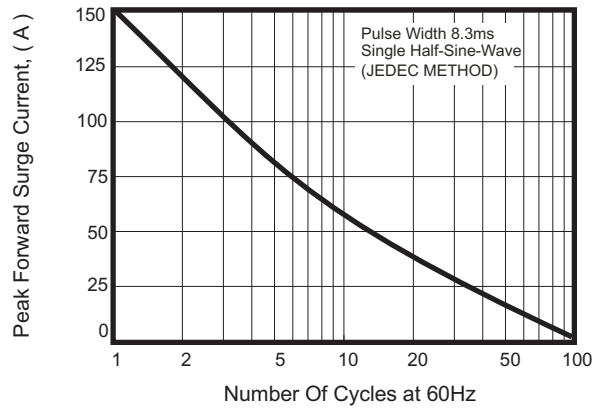


Fig.3 - Typical Instantaneous Forward Characteristics

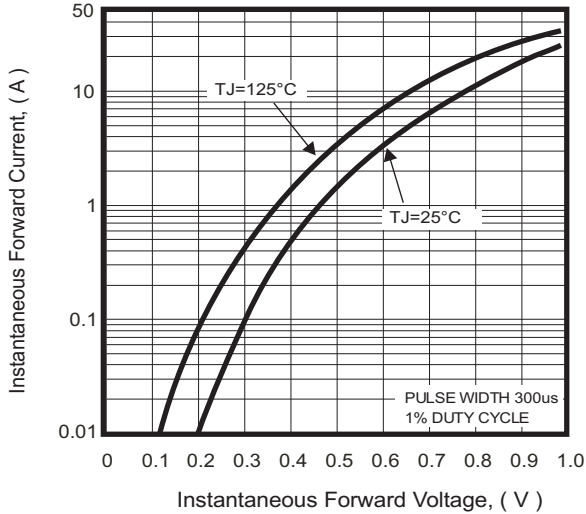


FIG.4- Typical Revers Characteristics

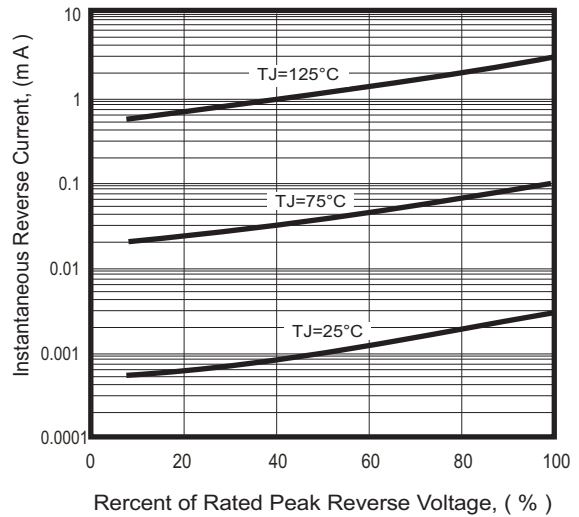


FIG.5- Typical Junction Capacitance

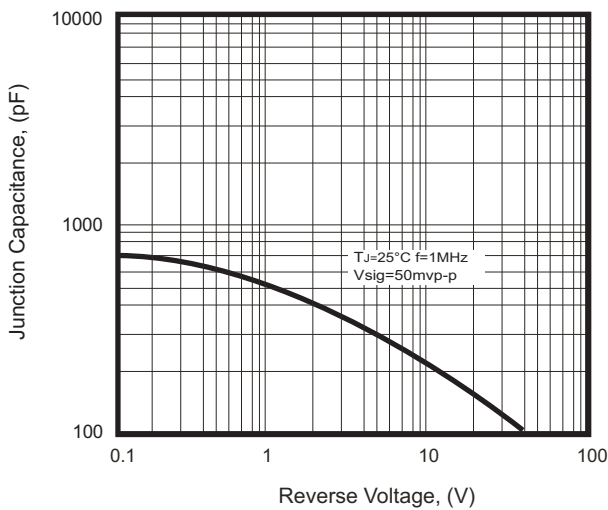
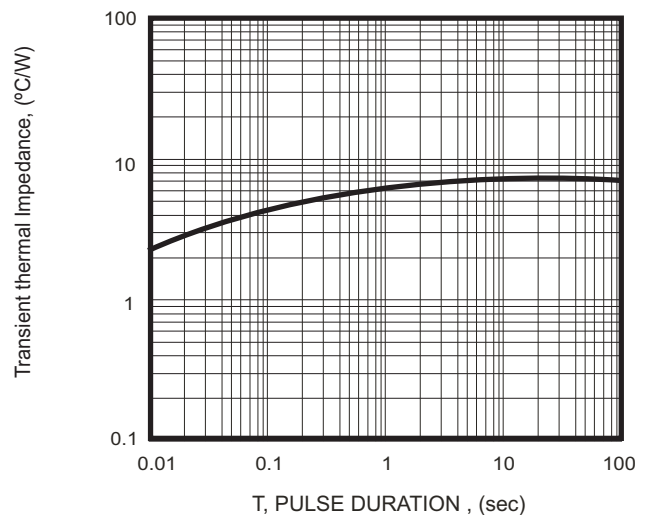
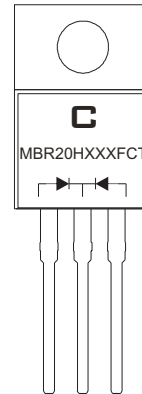


FIG.6- Typical Transient thermal impedance



Marking Code

Part Number	Marking code
MBR20H100FCT	MBR20H100FCT
MBR20H150FCT	MBR20H150FCT
MBR20H200FCT	MBR20H200FCT



XXX = Product type marking code
 C = Comchip Logo

Standard Packaging

Case Type	TUBE PACK		
	TUBE (pcs)	Box (pcs)	CARTON (pcs)
ITO-220AB	50	2,000	8,000